

EPO-TEK<sup>®</sup> H20E-8 Technical Data Sheet For Reference Only

Electrically Conductive, Silver Epoxy

| Date:                | July 2019                      |              | Recommended Cure: 150°C / 1 Hour                    |
|----------------------|--------------------------------|--------------|---|
| Rev:                 | IV                             |              |   |
| No. of Components:   | Two                            |              | Minimum Alternative Cure(s):                        |
| Mix Ratio by Weight: | 1:1                            |              | May not achieve performance properties listed below |
| Specific Gravity:    | Part A: 2.72                   | Part B: 4.33 | 150°C / 5 Minutes                                   |
| Pot Life:            | 3 Days                         |              | 120°C / 15 Minutes                                  |
| Shelf Life- Bulk:    | Six months at room temperature |              | 80°C / 90 Minutes                                   |

## NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

**Product Description:** EPO-TEK® H20E-8 is a two component, silver-filled epoxy system designed specifically for chip bonding in microelectronic and optoelectronic applications. It is a higher viscosity and higher thixotropic version of EPO-TEK® H20E.

**Typical Properties:** Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results. Data below is not guaranteed. To be used as a guide only, not as a specification. \* denotes test on lot acceptance basis

| PHYSICAL PROPERTIES:                    |             |           |  |  |  |
|---|-------------|-----------|--|--|--|
| * Color (before cure):                  | Part A: Sil | ver l     | Part B: Silver   |  |  |
| * Consistency:                          | Thixotropi  | c paste   |  |  |  |
| * Viscosity (23°C) @ 20 rpm:            | 10,0        | 00-20,000 | cPs  |  |  |
| Thixotropic Index:                      |             | 4.9       |  |  |  |
| * Glass Transition Temp:                |             | ≥ 80      | °C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min) |  |  |
| Coefficient of Thermal Expansion (CTE): |             |           |  |  |  |
| Below Tg:                               |             | 26        | x 10 <sup>-6</sup> in/in°C                                       |  |  |
| Above Tg:                               |             | 111       | x 10 <sup>-6</sup> in/in°C                                       |  |  |
| Shore D Hardness:                       |             | 66        |  |  |  |
| Lap Shear @ 23°C:                       |             | 1,216     | psi  |  |  |
| Die Shear @ 23°C:                       |             | ≥ 5       | Kg 1,778 psi   |  |  |
| Degradation Temp:                       |             | 470       | C  |  |  |
| Weight Loss:                            |             |           |  |  |  |
| @ 200°C:                                |             | 0.25      | %  |  |  |
| @ 250°C:                                |             | 0.37      | %  |  |  |
| @ 300°C:                                |             | 0.79      | %  |  |  |
| Suggested Operating Temperature:        |             | < 350     | °C (Intermittent)  |  |  |
| Storage Modulus:                        |             | 791,453   | psi  |  |  |
| Ion Content:                            | CI::        | 141 ppm   |  |  |  |
|   | NH4+:       | 265 ppm   |  |  |  |
| * Particle Size:                        |             | ≤ 45      | microns  |  |  |
| ELECTRICAL AND THERMAL PROPERTIES:      |             |           |  |  |  |
| Thermal Conductivity:                   |             | 3.5       | W/mK   |  |  |
| * Volume Resistivity @ 23°C:            |             | ≤ 0.0004  | Ohm-cm   |  |  |

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## **EPO-TEK® H20E-8 Advantages & Suggested Application Notes:**

- Especially recommended for use in high speed epoxy chip bonding systems where very fast cures are desired.
- Suggested for JEDEC Level III and II for plastic IC packaging.
- Capable of resisting TC wire bonding temperatures in the range of 300°C to 400°C.
- Ease of use: apply by dispensing, screen printing, die-stamping, or by hand.
- Especially suited for high power devices and high current flow; high power LEDs.
- Opto-electronic packaging material: LED, LCDs, and fiber optic components.